Composite Transistor For high speed switching Silicon N-channel + P-channel MOSFET

DESCRIPTION

RT3U33M is a composite transistor built with INK0003AX and INJ0003AX chips in SC-88 package.

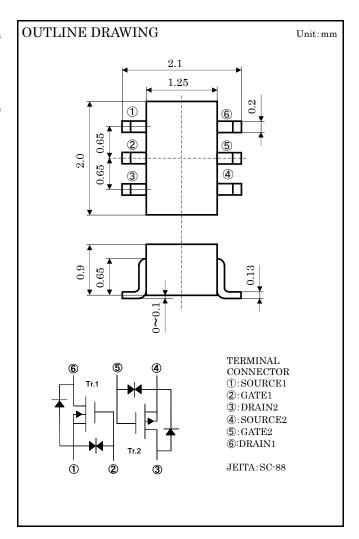
FEATURE

- •Input impedance is high, and not necessary to consider a drive electric current.
- •Vth is low, and drive by low voltage is possible. Vth= $0.6 \sim 1.2 \text{V}$
- •Low on Resistance. Ron= 0.9 / 2 Ω (Tr1/Tr2) TYP
- ·High speed switching.
- *Small package for easy mounting.

APPLICATION

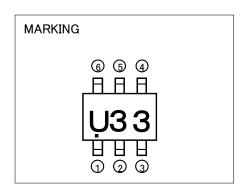
high speed switching, Analog switching

*P-channel MOSFET Tr2's minus sign is omitted



MAXIMUM RATING (Ta=25°C)

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SYMBOL	PARAMETER	RATING	UNIT	
$V_{\mathrm{DSS}}$	Drain-source voltage	20	V	
VGSS	Gate-source voltage	±8	V	
ID	Drain current	200	mA	
$P_{D}$	Total power dissipation(Ta=25°C)	150	mW	
$T_{\mathrm{ch}}$	Channel temperature	+125	°C	
$T_{ m stg}$	Range of Storage temperature	-55 <b>~</b> +125	°C	



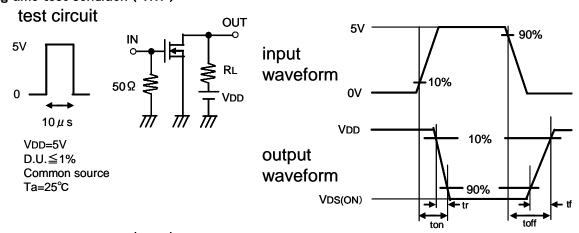
# RT3U33M

Composite Transistor For high speed switching Silicon N-channel + P-channel MOSFET

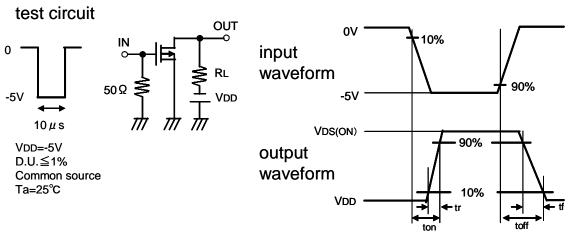
# ELECTRICAL CHARACTERISTICS (Ta=25°C)

Symbol	Parameter	Test conditions		Limits			Unit
				Min	Typ	Max	Unit
V(BR)DSS	Drain-source breakdown voltage	$I_{D}=100  \mu  A,  V_{GS}=0  V$		20	-	-	٧
Igss	Gate-source leak current	$V_{gs}=\pm 5V, V_{DS}=0V$		-	-	±0.5	μΑ
IDSS	Zero gate voltage drain current	V _{DS} =20V,V _{GS} =0V		_	-	50	μΑ
$V_{th}$	Gate threshold voltage	$I_D=250 \mu A, V_{DS}=V_{GS}$		0.6	-	1.2	٧
Lv. I	Forward transfer admittance	V _{DS} =10V, I _D =0.1A	Tr1	_	300	-	mS
Yfs			Tr2	-	280	-	
Rds(on)	Static drain-source on-state resistance	I _D =100mA, V _{GS} =4.0V	Tr1	-	0.9	-	Ω
FLDS(ON)			Tr2	_	2.0	-	
Ciss	Input capacitance	V _{DS} =10V, V _{GS} =0V,f=1MHz	Tr1	-	34	-	pF
			Tr2	_	37	_	
$C_{oss}$	Output capacitance	V _{DS} =10V, V _{GS} =0V,f=1MHz	Tr1	_	8.5	_	pF
			Tr2	_	12	_	ρı
ton		V _{DD} =5V , I _D =10mA V _{GS} =0∼5V	Tr1	-	14	-	ns
	0 11 11 11		Tr2	_	16	_	
toff	Switching time		Tr1	-	85	-	
			Tr2	_	110	_	

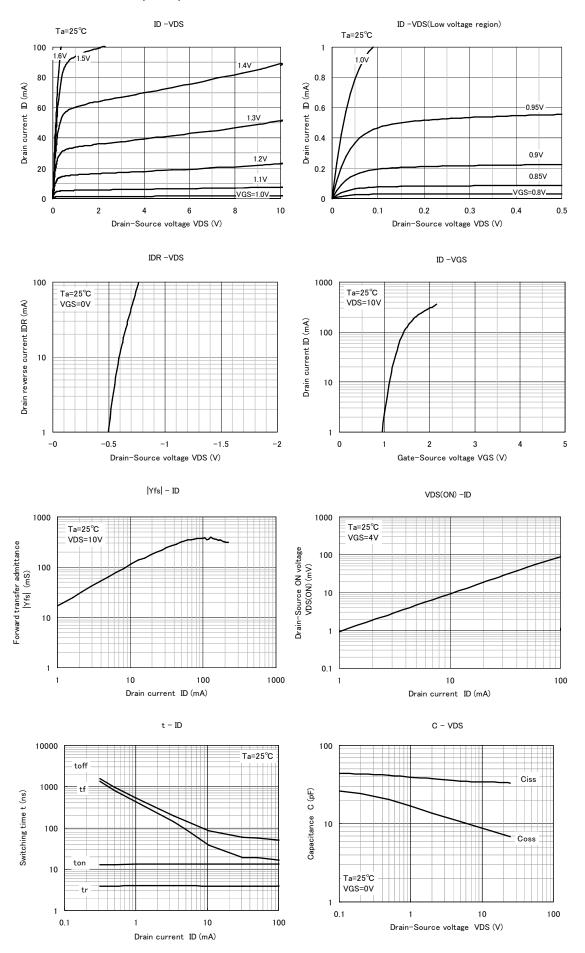
# Switching time test condition (Tr.1)



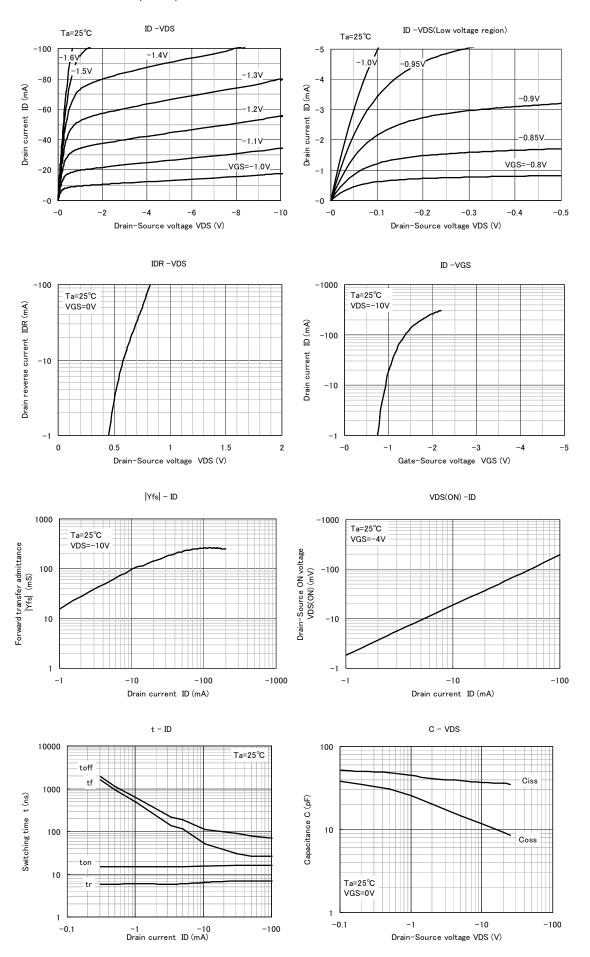
# Switching time test condition (Tr.2)



## TYPICAL CHARACTERISTICS (Tr.1)



## TYPICAL CHARACTERISTICS (Tr.2)





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